

# 13-MEMORY TONE/PULSE DIALER

### **GENERAL DESCRIPTION**

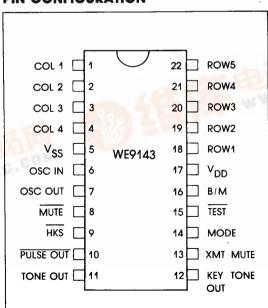
The WE9143 is a monolithic integrated circuit. It contains 13-Memories which can perform Tone/Pulse switchable dialing functions and Long Distance Service Company (Such as MCI, SPRINT) access codes operations for modern telephone set design. It is fabricated in CMOS technology thus has good performance in low voltage, low power operations. Three 16-digits direct dialing memories are added for convenient emergency calls (such as fire, police, doctor) operations. Wide operating voltage range and low memory retention current facilitate this chip excellent for battery-free direct line powered operation.

### **FEATURES**

- DTMF/Pulse Switchable Dialer.
- Stores ten 16-digits numbers for repertory dialing
- Three 16-Digits Numbers for Emergency Calling.
- Pulse to Tone Keypad for Long Distance Call Operation.
- One 31-Digits for Last Number Redial Memory.
- Auto Pause Access for PABX Operation; 3.1 sec. per Pause.
- Dialing length is unlimited, but if the dialing length of normal-dialing overstep 31 digits then redial is inhibited.
- Easy Operation with Redial, Store, Auto & Pause Keypads.
- Key-Tone Output for Valid Keypad Entry Recognition.
- Uses Standard 2-of-9 Matrix Keyboard.
- Electronic Keypad Input is Available; Low Active.
- Uses Inexpensive 3.579545MHz Television Color-Burst Crystal.
  - Pin Selectable for Break/Make Ratio.

- Memory Retention Current < 0.2 μA at V<sub>DD</sub> = 1.0V, ON-HOOK.
- Wide Operation Voltage Range: 2.0V ~ 5.5V.
- 22-Pin Dual-in-Line Package.

### PIN CONFIGURATION



TONE/PULSE

odf.dzsc.com



### **KEYBOARD FUNCTION**

R: Redial

S: Store

A: Auto Dialing

P: Pause

EM1-EM3: Emergency 1-3

P-T: Pulse to Tone Switch

COL1	COL2	COL3	COL4	
1	2	3	EM1	-ROW1
4	5	6	EM2	-ROW2
7	8	9	ЕМ3	-ROW3
*	0	#	P→ī	-ROW4
R	S	Α	P	-ROW5

## **ABSOLUTE MAXIMUM RATINGS**

CHARACTERISTICS	SYM	RATING	UNIT	
DC Supply Voltage	V <sub>DD</sub>	6.0	V	
Input Voltage Range	V <sub>IN</sub>	-0.5 to V <sub>DD</sub> +0.5	٧	
Power Dissipation Per Package	РО	500 (for $T_A = -25 \text{ to } +60 \text{ C}$ )	mW	
Operating Temperature	TA	-25 to +85	°C	
Storage Temperature	TSTG	-65 to +150	°C	

# DC. ELECTRICAL CHARACTERISTICS

 $(V_{DD}=2.5V, T_A=25^{\circ}C, unless otherwise noted)$ 

CHARACTERISTICS	SYM	TEST	TEST C	TEST CONDITION LIMIT		LIMIT		
		CKT.			MIN	TYP	MAX	UNIT
			Tone		2.0	_	5.5	
Operating Voltage	V <sub>DD</sub>		Pulse		2.0	-	5.5	V
			Memory		1.0	_	5.5	1
Operating Current	los		Tone	Note 1,4,6	_	0.6	2	
	IOP		Pulse	11010 1,4,0	_	0.2	0.5	mA
Memory Retention Current	IMR	В	HKS = 1, T	A=25°C,	_	0.1	0.2	μΑ
Standby Current	IS	Α	Note 1,2,	3,5,6	-	0.1	5	μA
Tone Output	V <sub>TO</sub>	С	Row Gro R <sub>L</sub> = 10 κΩ		130	150	170	mVrms
Pre-Emphasis		D		Group/Row / <sub>DD</sub> =2.0-5.5V	1	2	3	dB
DTMF Distortion	THD	D	R <sub>L</sub> = 10K, I	Note 7, 8	-	-30	-23	dB

		TEST			LIMITS			
CHARACTERISTICS	SYM	СКТ	TEST CONDITIOONS	MIN	TYPE	MAX	UNIT	
Tone Output External Load Impedance	RL		THD< -23dB	10	_	_	ΚΩ	
Tone Output DC Level	V <sub>DC</sub>	D	V <sub>DD</sub> =2.0-5.5V	0.5V <sub>DD</sub>	_	0.6V <sub>DD</sub>	-	
Tone Output Sink Current	1 <sub>TL</sub>	E	V <sub>TO</sub> = 0.5V	0.2	-	-	mA	
Pulse Output Drive Current	I <sub>PH</sub>	E	V <sub>PO</sub> = 2.0V	-0.2	, <b>-</b>	-	mA	
Sink Current	I <sub>PL</sub>	F	$V_{PO} = 0.5V$	0.2	-	-		
Mute Output Drive Current	IМН	E	V <sub>MO</sub> =2.0V	-0.2	-	-	mA	
Sink Current	I <sub>ML</sub>	] -	V <sub>MO</sub> =0.5V	2		_		
Key Tone Output Drive Current	IKH	Н	V <sub>KO</sub> =2.0V	-0.5	<b>-</b>	-	mA	
Sink Current	1 <sub>KL</sub>	E	$V_{KO} = 0.5V$	0.5				
XMT Mute Drive Current	LH	E	V <sub>LO</sub> =2.0V	-0.2		-	mA	
Sink Current	IIL	] -	$V_{LO} = 0.5V$	0.2	-	-		

# AC. ELECTRICAL CHARACTERISTICS

		TEST		LIMITS			
CHARACTERISTICS	SYM	CKT	CKT TEST CONDITIOONS		TYPE	MAX	UNIT
Key-in Debounce	TKID		TEST = 1, Note 8,9,10	-	20	-	mS
Key-released Debounce	TKRO		TEST = 1, Note 8,9,10	-	20	_	mS
Key-Tone Delay	T <sub>MD</sub>		TEST = 1, Note 2, 4, 10	-	20		mS
	т		TEST = 1, $B/M = 1$	_	40	-	mS
Pulse Mute Delay	TMD		Note 8, 9 B/M=0	_	33.3	_	
Dec Deit Deurs	_		TEST = 1, $B/M = 1$	-	40	-	mS
Pre-Dgit Pause	TPDP		Note 8, 9 B/M=0	-	33.3	-	
Pulse Rate	FPR		TEST = 1 Note 8	-	10	_	PPS
ruise kuie	, bk		TEST=0	-	600	_	



CHARACTERISTICS	SYM	СКТ	IEST CO	NDITION		LIMIT		UNIT
					MIN	TYP	MAX	OINII
Inter Digit Pause	T <sub>IDP</sub>		TEST = 1		_	800		mS
	TIDP	,	TEST = 0		-	13.3		1113
Break/Make Ratio	D 14	į	B/M=1		_	60:40	_	
break/Make Ratio	B:M		B/M=0 Note 8	66.6: 33.3	_	%		
Tone Duration	T <sub>TD</sub>		Auto Dia	ling Note 8	-	100	_	mS
Inter Tone Pause	TITP		Auto Dia	ling Note 8	_	105	-	mS
	F1	С	ROW 1,	NOTE 8	_	699	-	
Row Group	F2		ROW2, I	ROW2, NOTE 8		766	-	Hz
Frequency	F3		ROW3, NOTE 8		-	848	-	
	F4		ROW4, I	NOTE 8	-	948	_	
	F5		COL1, N	OTE 8	_	1216	-	
Column Group Frequency	F6	С	COL2, N	COL2, NOTE 8		1332	-	Hz
riequericy	F7		COL3, N	IOTE 8	-	1472	-	
Key Tone Frequency	FK		Note 8		_	1.2	-	KHz
Input Voltage Low	$v_{IL}$		Pins, 1-4	, 9, 14, 15	GND	-	0.3V <sub>DD</sub>	
Input Voltage High	V <sub>IH</sub>		17 & 18-22		0.7V <sub>DD</sub>	-	V <sub>DD</sub>	
Keypad Input Drive Current	I <sub>KD</sub>	F	V <sub>I</sub> = 0 V		4	10	30	μΑ
Sink Current	IKS	E, G	V <sub>1</sub> =2.5V		200	400		
Control Pin Input	IN		Pins 9, 1	4, 15, 17	-	± 10 <sup>5</sup>	±0.1	μΑ

Note 1 :  $\overline{HKS} = 0$ 

Note 2: In DTMF Mode

Note 3: In Pulse Mode

Note 4: Keyboard Entry, including Auto

Dialing

Note 5 : No Keyboard Entry Note 6 : All Output Unloaded

Note 7 : Dual Tone Multi-Frequency Distortion

is measured in terms of total out-of band power related to sum of row & column fundamental power

Note 8 : Crystal parameters defined as Rs <

100 $\Omega$  Lm = 96mH Cm = 0.25PF

Ch = 5PF, F = 3.579545MHz & CL = 18PF

 $F < \pm 200PPM$ 

Note 9 : Referred to Pulse Mode Time

Diagram

Note 10: Referred to DTMF Mode Time

Diagram

### FUNCTION DESCRIPTION

A. ROW-COLUMN INPUT (PIN 1~4 & 18~22) The keypads input is compatible with the standard 2-of-9 keyboard. In normal operation, any single button is pushed to produce dual tone, pulses or function. Activation of two or more buttons will result in no response, except for single tone. TABLE 1 illustrates the address keypads function, in detail.

	OUTPUT	ACTIVE	LOW INPUTS	OUTPUT TONE (Pin 11)
		ROW (Pin 18-21)	COLUMN (Pin 1-3)	PULSE (Pin 10)
	5	One	One	Dual Tone
	Normal Pin 15=1)	Two or More	One	
(0=	Nor (Pin )	One	Two or More	Pin 11=0
TONE (Pin 14=0)		Two or More	Two or More	
(Pir		One	One	Dual Tone
	Signal (Pin 15=0)	Two or More	Two or More One C	Column Tone
-	Sig 7 Jin	One	Two or More	Row Tone
		Two or More	Two or More	Pin 11=0
		One	One	10pps
	5=1	Two or More	More One	
4=1	10 pps Pin 15=1	One	Two or More	Pin 10=1
ř.	1	Two or More	Two or More	_
PULSE (Pin 14=1)		One	One	600pps
SJUG	pps 15=0	Two or More	One	
_	600 p	One	Two or More	Pin 10=1
	7	Two or More	Two or More	

Note 1: In pulse mode, Pin 10=1 for \* & # buttons.

Note 2: In pulse mode, always Pin 11=0, in DTMF mode, always Pin 10=1.

Note 3: Pin 10=1, Pin 11=0 for any button in Row 5 & Column 4, regardless of mode.



### B. OSC IN, OSC OUT

An built-in inverter provides oscillation with an inexpensive 3.579545MHz television color-burst crystal. The oscillator ceases when a keypad input is not sensed. Most crystals do not vary more than  $\pm 0.02\%$ .

### C. MUTE

The mute output is a conventional CMOS inverter that pulls to  $V_{DD}$  with no keyboard input and pulls to  $V_{SS}$  when an address keypads entry is sensed (excluding the \* & # keypads, in pulse mode), that is, any keypad in row 5 and column 4 is pushed, then mute out keeps high level still.

### D. HKS

The  $\overline{HKS}$ (Hook Switch) input is used to detect the handset in ON-HOOK or OFF-HOOK. In ON-HOOK state,  $\overline{HKS}$ =1, the keyboard input is disabled. In OFF-HOOK state,  $\overline{HKS}$ =0.

### E. PULSE OUT

In DTMF mode, the pulse out keeps high level regardless of leyboard entry. In pulse mode, this output sends a chain of pulses to correspond the address keypad input, but keeps high level for \* and # entry.

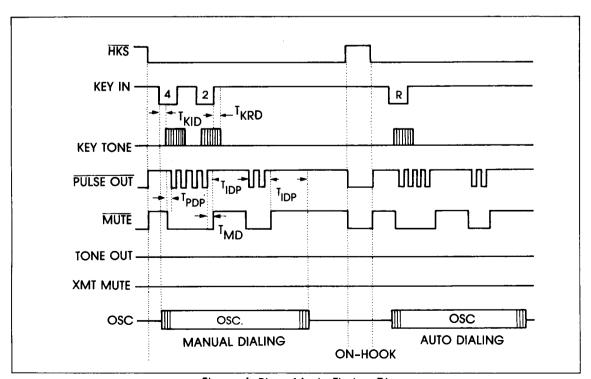


Figure 1 Pluse Mode Timing Diagram

### F. TONE OUT

In normal dialing, the tone duration depends on key-in lasting. When keypad is pressed less than 100ms, the tone duration will be fixed to 100ms. In opposite, the tone duration will last as long as key-in continuance. The inter-tone-pause will be different under following condition: when key-released duration continues less than 105ms, it will be fixed to 105ms, otherwise it will be equal the duration of keyreleased. When redialing and memory dialing, the tone duration and inter-tonepause are internally set to be 100ms and 105ms respectively. During pulse dialing, it always keeps at low state regardless of keypad input.(See Figure 2)

### G. KEY TONE OUT

The key tone output is a conventional CMOS inverter. A NPN transistor is needed to drive a piezo. The output frequency is 1.2KHz. The key tone acturates, after valid key entry has been detected, and ceases at the time of button released.

#### H. XMT MUTE

The XMT MUTE is a conventional CMOS inverter. In DTMF mode, the output actuates in the duration of DTMF signal is sending. But, the output always keeps low in pulse mode. It can be used for muting operation in Tone mode or control LED for indicating(See Application Circuit).

#### I. MODE

Pulls pin 14 to  $V_{DD}$ , the dialer is in pulse mode. On the contrary, it is in DTMF mode.

### J. TEST

In normal operation, ties the  $\overline{\text{TEST}}$  Pin to  $V_{DD}$ , the single tone is inhibited and pulse rate is 10 pps. In testing operation, ties the TEST pin to GND, single tone can be created with the method shown in TABL 1, and all of the time parameter in pulse dialing is faste by 60 times.

#### K. B/M

The Break/Make ratio is 60:40, if B/M=1, and is 66.6:33.3 if B/M=0. This pin influences nothing in DTMF mode.



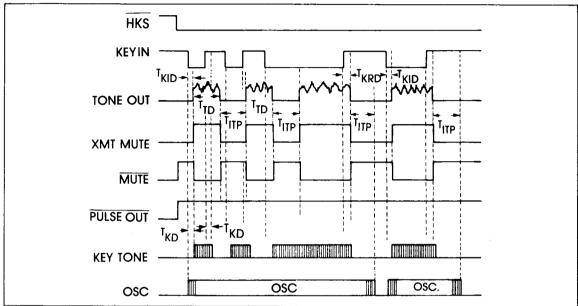


Figure 2[a] Tone Mode Normal Dialing Tim-ing Diagram

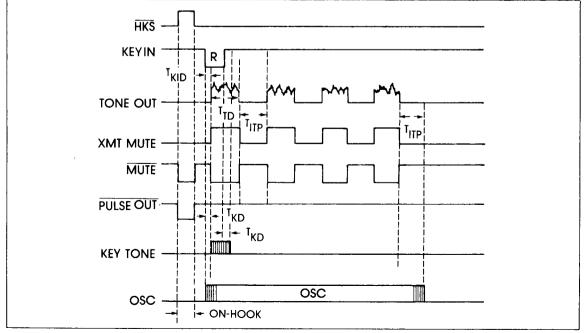


Figure 2[b] Tone Mode Redialing Timing Diagram

## **KEYBOARD OPERATIONS**

Note: 1. All the keyboard operations should be under OFF-HOOK condition.

2. D1 ~ Dn: 0-9. \*. #

### A. NORMAL DIALING

D1 , D2 ,..., Dn

### B. REDIALING

R, the last number will be dialed out automatically.

### C. STORE

S, D1, D2,..., Dn, S, Ln Ln: 0~9 Then, D1, D2, ... Dn will be stored in location Ln.

### D. MEMORY DIALING

A, Ln, then the number stored in location Ln will be diales out automatically.

### E. PAUSE KEY OPERATION

In some PABX or Long Distance Service, pause should be inserted in dialing sequence. The WE9143 provides stackable pause function (3.1 sec/Pause) which facillitates flexible applications.

- a. Dialing with Pause Key
  - 1. D1, P, D2, ..., DN

    Then the number will be dialed out as following sequence; D1, D2, ... Dn; without pause.
  - Redialing with Pause Key
     OFF-HOOK, R, then the signal will be
     dialed out automatically D1, pause
     3.1 sec., D2, ...Dn.
- b. Storing with Pause Key
  - 1. S, D1, P, D2, ... Dn S Ln then the number D1, P, D2, ... Dn will be stored

in Ln

Memory Dialing with Pause Key
 A Ln, then the output signal will be dialed as: D1, pause 3.1 sec., D2, ...
 Dn.

Note: Every Pause will occupy one digit of memory size.

#### F. EMERGENCY DIALING

WE9143 provides three memories for storing emergency numbers such as fire, police and doctor.

- a. Storing Emergency Numbers

  S D1 D2 ... Dn S EMn EMn:EM1-EM3

  Then the number D1, D2, .... Dn will be stored in EMn.
- b. Emergency Dialing
  Push EMn, the EMn will be dialed out in
  Pulse or Tone mode as selected.

#### G. PULSE TO TONE KEY OPERATION

The WE9143 provides one special function for long distance service company (such as MCI, SPRINT) access codes operations,

- a. Dialing with Pulse to Tone Key D1, D2, ..., Dn, P-T, D1', D2', ... Dn' D1, D2, ... Dn, D1', D2', ... Dn', without pause.
- b. with Pulse to Tone Key
  OFF-HOOK, R, then the signal will be
  dialing out automatically as same sequence of dialing with Pulse to Tone key,
  but has a 3.1 sec pause during changing mode.

Note: 1. If in Tone mode P-T as pause function.





- It can be reset to Pulse mode only in the operation of ON-HOOK.
- c. Storing the Long Distance Service Company Code to Memory S, D1, D2, ..., Dn, P-T D1', D1', D2', ..., Dn', S, Ln Then the number sequence will be stored in location Ln'.
- d. Memory Dialing with Pulse to Tone Key Select Pulse mode.

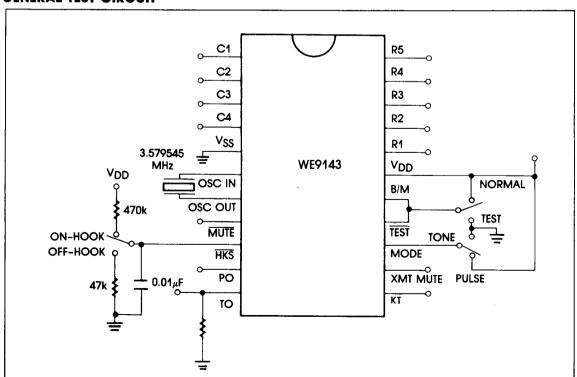
A, Ln D1, D2,..., Dn, pause 3.1 sec., D1', D2'. .... Dn'

- Note: 1. If in Tone mode, it will auto insert a pause at P-T position.
  - 2. If the LDC codes are stored in EM1–EM3, the operation will

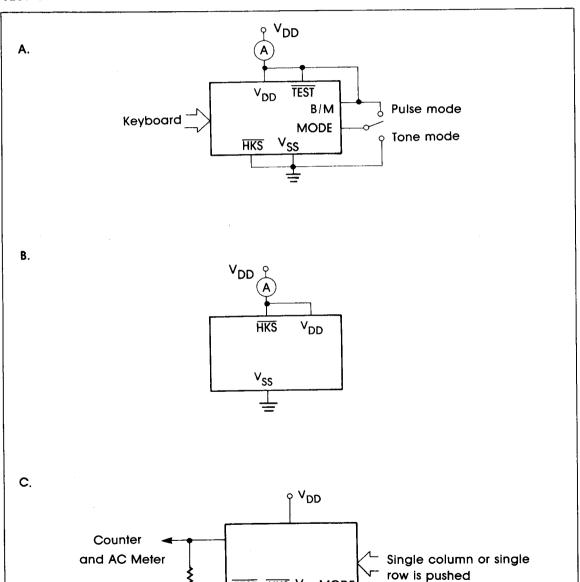
### H. MIXED DIALING

Mix-dialing is acceptable and has no limit on the dialing length of above listed items operation.

### **GENERAL TEST CIRCUIT**



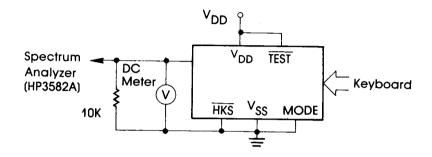
# TEST CIRCUIT



TEST HKS V<sub>SS</sub> MODE



D.

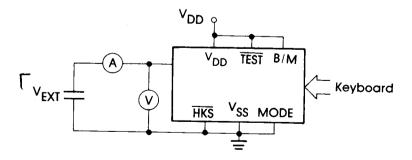


DIST<sub>db</sub> = 20 log 
$$\frac{\sqrt{[V_1]^2 + [V_2]^2 + .... + [V_n]^2}}{\sqrt{[V_L]^2 + [V_H]^2}}$$

- \* V1, ..., Vn are extraneous frequency (ie intermodulation and harmonic) components in the 500 Hz to 3400 Hz band.
- $^{\ast}$   $\text{V}_{L}$  ,  $\text{V}_{H}$  , are the individual frequency components of the DTMF signal.

Note: Whether keyboard is pushed refer to the DTMF mode timing diagram.

E.

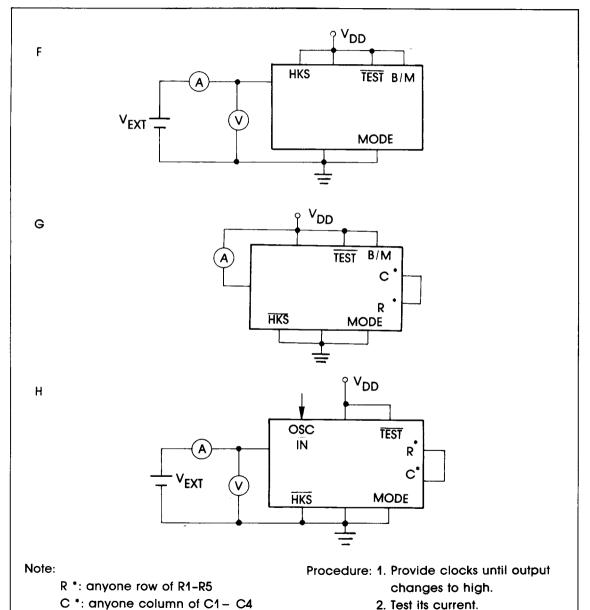


Note: Whether keyboard is pushed refer to the DTMF mode timing diagram.

2. Test its current.

order to speed up testing.

Note:  $\overline{\text{TEST}}$  pin can be combined with  $V_{SS}$  in



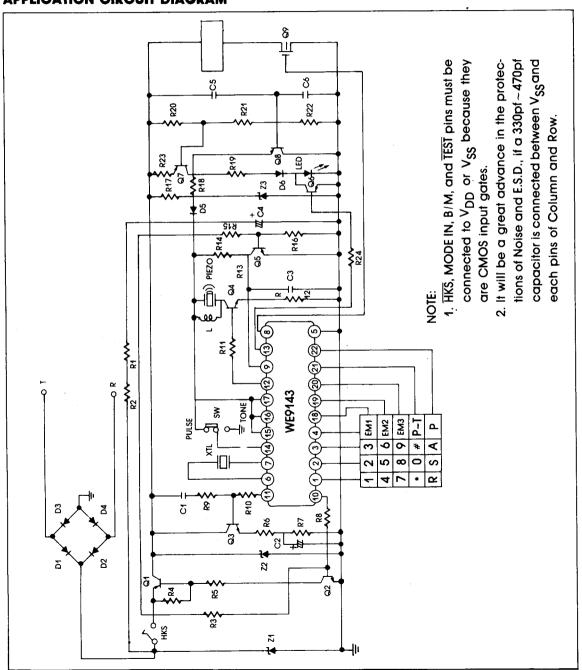
Isink = I/(1-Duty Cycle)

ampere meter.

I is the net DC current measured from



## **APPLICATION CIRCUIT DIAGRAM**



### CIRCUIT DESCRIPTION

- A. The circuit is line powered through a diode bridge for rectifying and regulated by a regulation circuit which consists of Q7, Q8, R18-R23, D5 and C5, C6, Q7, Q8 are always in active region. C5 ensures a high regulator impedance for AC siguals. This capacitor value should not be too large in order to have short response time of system. C6 is a compensatory capacitor. C4 must be a low leakage capacitor and D5 blocks up the path from C4 to Q8 for holding the voltage in C4.
- B. In ON-HOOK state, R1, R2 provide the flow path for memory data retention current and make the circuit to satisfy the requirement of EIA-RS470 which require DC input impedance to be higher than  $10M\Omega$ and R2 are  $22M\Omega$ separately when used in paraillel with other three same telephone sets. The memory data retention current of dialer is furnished through R1, R2, and C1, all other circuits are floated to decrease the need of data retention current in ON-HOOK state.
- C. Dialing pulses are sent by controlling the states of Q1 and Q2. In DTMF mode, Q1 and Q2 are always saturated, and dialing tone is sent through the amplifier which consists of R6, R7, R9, R10, C1, C2 and Q3, R9, C1 is a RC feedback circuit, it keeps the tone output unaffected by different transistor.
- D. Z1 and Z2 prodect the whole circuit from surge voltage and over-large signal on telephone line when off hook, Z3 limits the eoltage supplied to WE9143.

- E. L, Q4 and piezo make a tuning circuit and generate a key tone when the keypad is pushed. R12 is a current-limited resistor.
- F. Q9 provides the muting for receiver and transmitter when dialing, R19, R24, D6, Q6 and LED implement the dialing indication.
- G. R13-R16, C3 and Q5 make a detecting circuit of hook-switch. When ON-HOOK, Q5 is turned off. R13 is pulled high in a short time. In OFF-HOOK state, C3 protects HKS from spikes effect and R13 is pulled low while Q5 is turned on.
- H. SW furnishs the selection of dialing mode for user.



		<del> </del>		
22M	R18	110Ω	D5-D6	IN4148
22M	R19	330Ω	Z1	IN5379
910ΚΩ	R20	1.6Ω	<b>Z2</b>	1N4743
33ΚΩ	R21	1.2ΚΩ	Z3	RD4.3EB3
4.7ΚΩ	R22	5.1Ω	Q1	2SA640
<b>36</b> Ω	R23	10Ω	Q2	2N5551
62Ω	R24	33ΚΩ	Q3	FC8050
10ΚΩ	C1	0.02μF	Q4 ~ Q6	2N9014
100ΚΩ	C2	4.7μF/16V	Q7~Q8	2N4403
5.1ΚΩ	C3	0.5μF	Q9	AVN1106
33ΚΩ	C4	100μF/16V	XTL	3.579545MHz
1.2ΚΩ	C5	2.2μF/25V	ICI	WE9143
10ΚΩ	C6	0.01 μF		
330ΚΩ	D1	1N4004		
330ΚΩ	D2	1N4004		
<b>82</b> ΚΩ	D3	1N4004		
10ΚΩ	D4	1N4004		
	22M 910KΩ 33KΩ 4.7KΩ 36Ω 62Ω 10KΩ 100KΩ 5.1KΩ 33KΩ 1.2KΩ 10KΩ 330KΩ 330KΩ 330KΩ	22Μ       R19         910ΚΩ       R20         33ΚΩ       R21         4.7ΚΩ       R22         36Ω       R23         62Ω       R24         10ΚΩ       C1         100ΚΩ       C2         5.1ΚΩ       C3         33ΚΩ       C4         1.2ΚΩ       C5         10ΚΩ       C6         330ΚΩ       D1         330ΚΩ       D2         82ΚΩ       D3	22Μ       R19 $330\Omega$ 910ΚΩ       R20 $1.6\Omega$ $33ΚΩ$ R21 $1.2ΚΩ$ $4.7ΚΩ$ R22 $5.1Ω$ $36Ω$ R23 $10Ω$ $62Ω$ R24 $33ΚΩ$ $10ΚΩ$ C1 $0.02μF$ $100ΚΩ$ C2 $4.7μF/16V$ $5.1ΚΩ$ C3 $0.5μF$ $33ΚΩ$ C4 $100μF/16V$ $1.2ΚΩ$ C5 $2.2μF/25V$ $10ΚΩ$ C6 $0.01μF$ $330ΚΩ$ D1 $1N4004$ $330ΚΩ$ D2 $1N4004$ $82ΚΩ$ D3 $1N4004$	22Μ       R19 $330\Omega$ Z1         910ΚΩ       R20 $1.6\Omega$ Z2 $33ΚΩ$ R21 $1.2ΚΩ$ Z3 $4.7ΚΩ$ R22 $5.1Ω$ Q1 $36Ω$ R23 $10Ω$ Q2 $62Ω$ R24 $33ΚΩ$ Q3 $10ΚΩ$ C1 $0.02μF$ Q4 ~ Q6 $10ΚΩ$ C2 $4.7μF/16V$ Q7 ~ Q8 $5.1ΚΩ$ C3 $0.5μF$ Q9 $33ΚΩ$ C4 $100μF/16V$ XTL $1.2ΚΩ$ C5 $2.2μF/25V$ ICI $10ΚΩ$ C6 $0.01μF$ $330ΚΩ$ D1 $1N4004$ $330ΚΩ$ D2 $1N4004$ $82ΚΩ$ D3 $1N4004$